

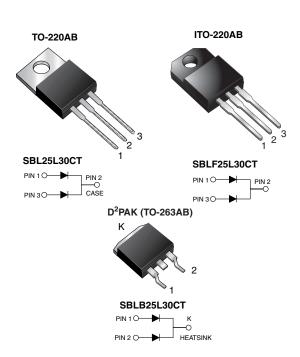
## SBL25L30CT, SBLF25L30CT, SBLB25L30CT

Vishay General Semiconductor

HALOGEN

FREE

## **Dual Low V<sub>F</sub> Common Cathode Schottky Rectifier**



#### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 12.5 A				
$V_{RRM}$	30 V				
I <sub>FSM</sub>	180 A				
V <sub>F</sub>	0.39 V				
T <sub>J</sub> max.	150 °C				
Package	TO-220AB, ITO-220AB, D <sup>2</sup> PAK (TO-263AB)				
Circuit configuration	Common cathode				

#### **FEATURES**

- Power pack
- Low power loss, high efficiency
- · Very low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D<sup>2</sup>PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
  Automotive ordering code:
  Base P/NHE3 (for ITO-220AB)
  Base P/NHM3 (for D<sup>2</sup>PAK (TO-263AB package))
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in low voltage, high frequency inverters, switching mode power supplies, freewheeling diodes, OR-ing diodes, DC/DC converters, and polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Base P/NHE3\_X - RoHS-compliant, AEC-Q101 qualified

("\_X" denotes revision code, e.g. A, B, ...)

Base P/N-M3 - RoHS-compliant, halogen-free, commercial grade

Base P/NHM3 - RoHS-compliant, halogen-free, AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 and M3 suffix meets JESD 201 class 1A whisker test, HE3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum



# SBL25L30CT, SBLF25L30CT, SBLB25L30CT

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MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	SBL25L30CT SBLB25L30CT SBLF25L30CT	UNIT	
Maximum repetitive peak reverse voltage		$V_{RRM}$	30	V	
Maximum average forward rectified current at T <sub>C</sub> = 95 °C	total device	I <sub>F(AV)</sub>	25		
	per diode		12.5	Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	180	, ,	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink, t = 1 min		$V_{AC}$	1500	V	

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
Maximum instantaneous forward valtage	V <sub>F</sub> <sup>(1)</sup>	12.5 A	T <sub>J</sub> = 125 °C	0.39	V	
Maximum instantaneous forward voltage			T <sub>J</sub> = 25 °C	0.49		
Maximum instantaneous reverse current at DC blocking voltage per diode	I <sub>R</sub> <sup>(2)</sup>	Rated V <sub>R</sub>	T <sub>J</sub> = 25 °C	0.90		
			T <sub>J</sub> = 100 °C	50	mA	
			T <sub>J</sub> = 125 °C	100		

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: pulse width  $\leq$  40 ms

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SBL25L30CT	SBLF25L30CT	SBLB25L30CT	UNIT
Typical thermal resistance from junction to case per diode	$R_{ heta JC}$	1.5	4.0	1.5	°C/W

ORDERING INFORMATION						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	SBL25L30CT-E3/45	1.85	45	50/tube	Tube	
ITO-220AB	SBLF25L30CT-E3/45	1.99	45	50/tube	Tube	
D <sup>2</sup> PAK (TO-263AB)	SBLB25L30CT-M3/I	1.35	I	800/reel	Tape and reel	
ITO-220AB	SBLF25L30CTHE3_A/P (1)	1.99	Р	50/tube	Tube	
D <sup>2</sup> PAK (TO-263AB)	SBLB25L30CTHM3/I (1)	1.35	I	800/reel	Tape and reel	

#### Note

 $^{(1)}$  AEC-Q101 qualified, available in ITO-220AB and D2PAK (TO-263AB)

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### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>C</sub> = 25 °C unless otherwise noted)

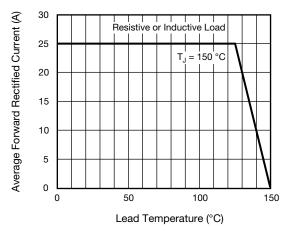


Fig. 1 - Forward Current Derating Curve

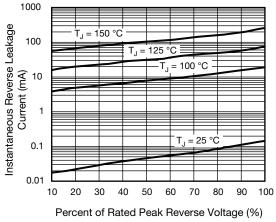


Fig. 4 - Typical Reverse Characteristics Per Diode

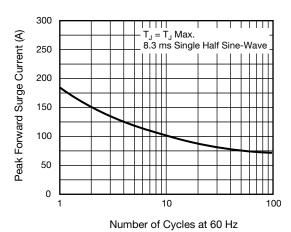


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

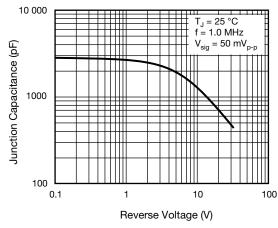


Fig. 5 - Typical Junction Capacitance Per Diode

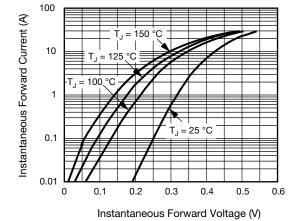


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

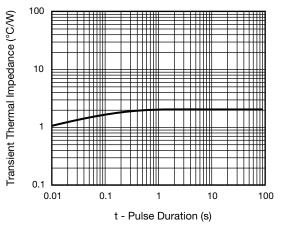


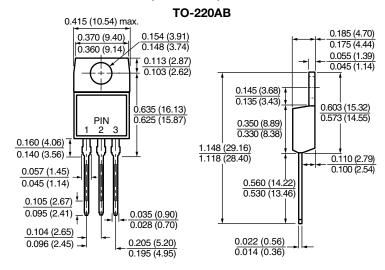
Fig. 6 - Typical Transient Thermal Impedance Per Diode

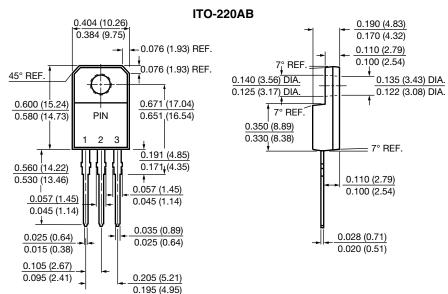




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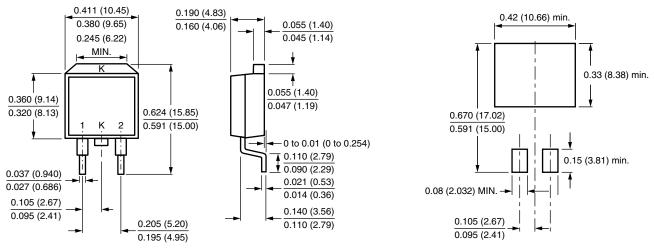
### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





### D<sup>2</sup>PAK (TO-263AB)

### **Mounting Pad Layout**





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